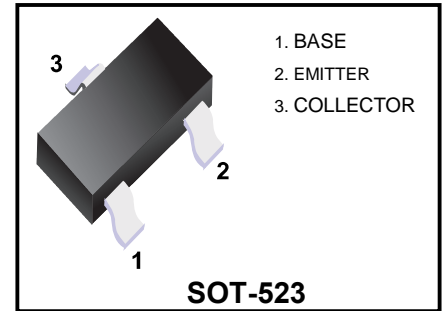


**TRANSISTOR (NPN)**

**FEATURES**

- ◆ Complimentary to S8550
- ◆ Collector Current:  $I_C=0.5A$



Marking Code	
S8050T	J3Y

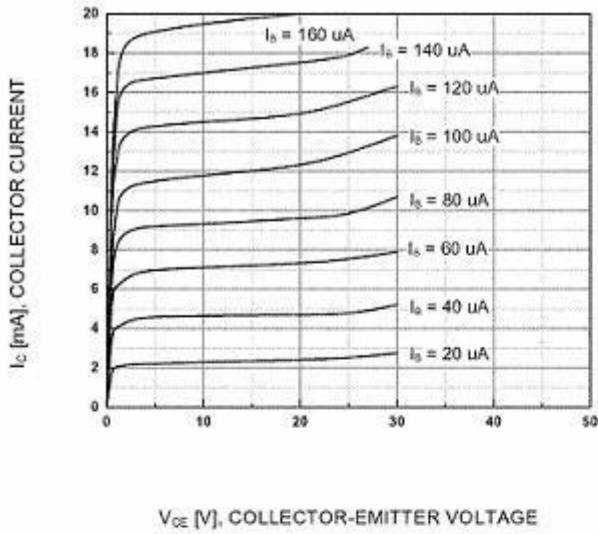
**MAXIMUM RATINGS (TA=25°C unless otherwise noted)**

Parameter	Symbol	Value	Units
Collector-Base Voltage	$V_{CBO}$	40	V
Collector-Emitter Voltage	$V_{CEO}$	25	V
Emitter-Base Voltage	$V_{EBO}$	5	V
Collector Current -Continuous	$I_C$	0.5	A
Collector Dissipation	$P_C$	0.3	W
Junction Temperature	$T_j$	150	°C
Storage Temperature	$T_{stg}$	-55-150	°C

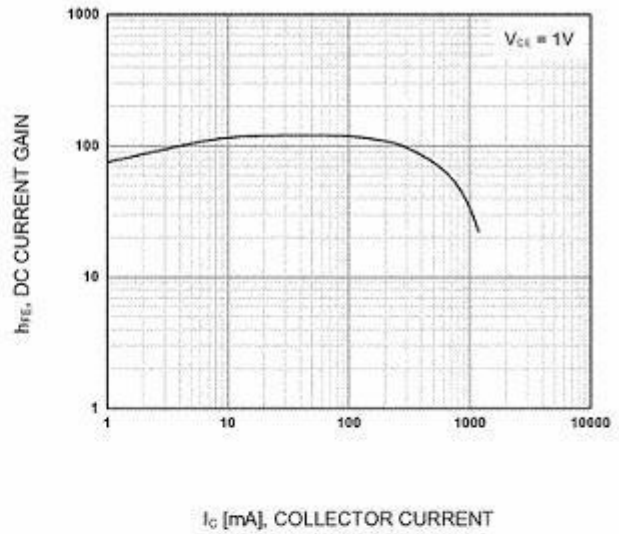
**ELECTRICAL CHARACTERISTICS (Tamb=25°C unless otherwise specified)**

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=100\mu A, I_E=0$	40			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=1mA, I_B=0$	25			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=100\mu A, I_C=0$	5			V
Collector cut-off current	$I_{CBO}$	$V_{CB}=40V, I_E=0$			0.1	$\mu A$
Collector cut-off current	$I_{CEO}$	$V_{CB}=20V, I_E=0$			0.1	$\mu A$
Emitter cut-off current	$I_{EBO}$	$V_{EB}=5V, I_C=0$			0.1	$\mu A$
DC current gain	$H_{FE(1)}$	$V_{CE}=1V, I_C=50mA$	200		350	
	$H_{FE(2)}$	$V_{CE}=1V, I_C=500mA$	50			
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=500mA, I_B=50mA$			0.6	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C=500mA, I_B=50mA$			1.2	V
Transition frequency	$f_T$	$V_{CE}=6V, I_C=20mA$ $f=30MHz$	150			MHz

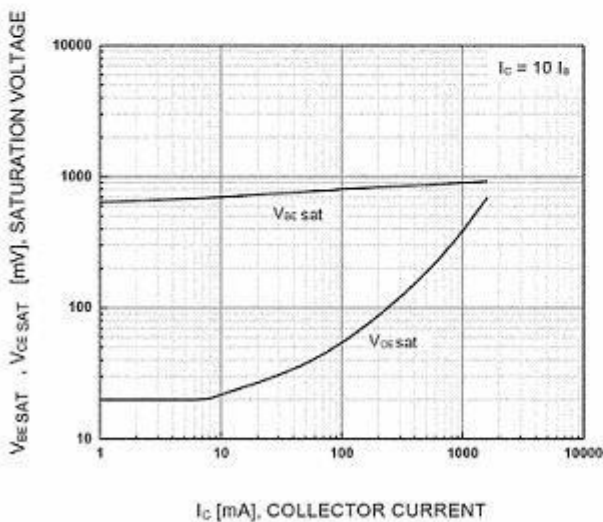
Typical Characteristics



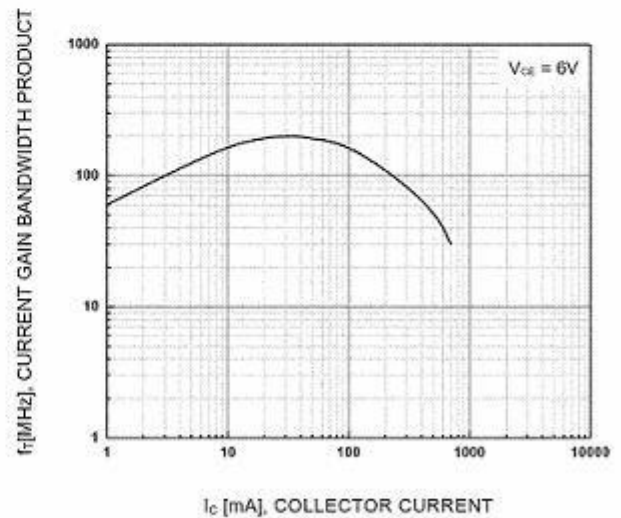
Static Characteristic



DC current Gain



Base-Emitter Saturation Voltage  
Collector-Emitter Saturation Voltage



Current Gain Bandwidth Product

**Ordering information**

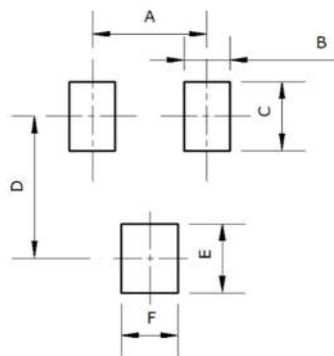
Package	Packing Description	Base Quantity	Packing Quantity
SOT-523	Tape/Reel,7"reel	3000pcs/Reel	24000PCS/Box 120000PCS/Carton

**Package Dimensions**

**SOT-523**

Dim.	Millimeter (mm)		mil	
	Min.	Max.	Min.	Max.
A	1.50	1.70	59	67
B	0.75	0.85	30	33
C	1.45	1.75	57	69
D	0.50TYP		0.020TYP	
E	0.90	1.10	35	43
G	0.00	0.10	0	4
H	0.60	0.80	24	31
J	0.10	0.20	4	8
K	0.15	0.35	6	14
L	0.26	0.46	10	18

**The recommended mounting pad size**



Millimeter (mm)	
Dim.	TYP
A	1.00
B	0.40
C	0.60
D	1.24
E	0.60
F	0.50

## Disclaimer

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